



PRELIMINARY

SOLID STATE DEVICES, INC.14005 Stage Road * Santa Fe Springs, Ca 90670
Phone: (562) 404-4474 * Fax: (562) 404-1773**Designer's Data Sheet****FEATURES:**

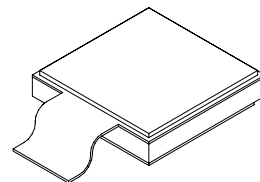
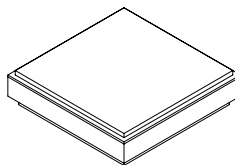
Optimized for 2.1V and 3.3V output power supplies. The SUPER SCHOTTKY series has been designed to provide ultra low forward voltage drops at low operating temperatures of 75°C.

- **Low V_F , less than 300mV at 75°C**
- **Low Reverse Leakage**
- **Surface Mountable**
- **Guard Ring for Overvoltage Protection and Ruggedness**
- **100°C Operating Temperature**
- **Hermetic Package**
- **TX, TXV and Space Level Screening Available**

Typical applications include parallel switching power supplies, converters, battery protection circuits, and redundant power sub-systems.

SED20HB25
SED20HE25**20 AMP**
25 VOLTS
SUPER SCHOTTKY
RECTIFIER

SEDPACK 1



Maximum Ratings	SYMBOL	VALUE	UNITS
Peak Repetitive Reverse and DC Blocking Voltage	V_{RRM} V_{RWM} V_R	25	Volts
Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, $T_J = 75^\circ\text{C}$)	I_o	20	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on I_o , allow junction to reach equilibrium between pulses, $T_J = 25^\circ\text{C}$)	I_{FSM}	150	Amps
Operating and Storage Temperature	Top & Tstg	-55 TO +100	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	2.0	°C/W

NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: SH0011A

SED20HB25 SED20HE25

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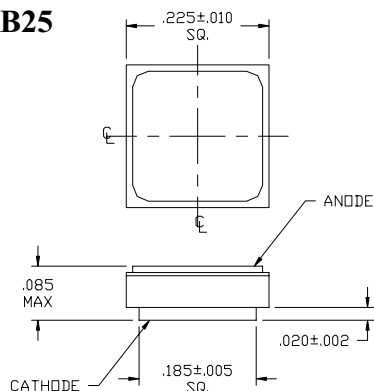
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Electrical Characteristics	SYMBOL	VALUE	UNITS
Instantaneous Forward Voltage Drop ($I_F = 10A_{DC}$, $T_J = 25^\circ C$, 300 μs Pulse) ($I_F = 20A_{DC}$, $T_J = 25^\circ C$, 300 μs Pulse)	V_{F1} V_{F2}	0.375 0.400	V_{DC}
Instantaneous Forward Voltage Drop ($I_F = 10A_{DC}$, $T_J = 75^\circ C$, 300 μs Pulse)	V_{F3}	0.300	V_{DC}
Reverse Leakage Current $T_J = 25^\circ C$, 300 μsec pulse minimum $V_R = 3.3V$ $V_R = 25V$	I_{R1} I_{R2}	3.0 15	mA mA
Reverse Leakage Current $T_J = 75^\circ C$, 300 μsec pulse minimum $V_R = 3.3V$ $V_R = 25V$	I_{R3} I_{R4}	45 125	mA mA
Reverse Leakage Current $T_J = 100^\circ C$, 300 μsec pulse minimum $V_R = 3.3V$ $V_R = 15V$	I_{R5} I_{R6}	100 215	mA mA
Junction Capacitance ($V_R = 5V_{DC}$, $T_J = 25^\circ C$, $f = 1MHz$)	C_J	1500	pF

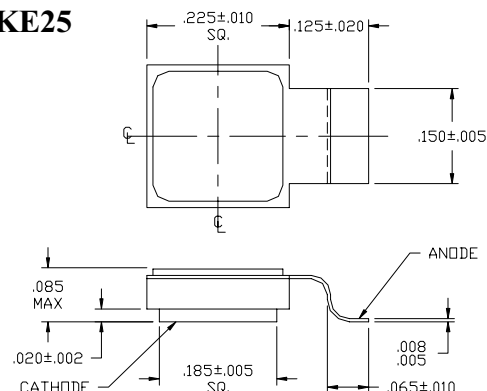
CASE OUTLINE:

P/N SED60KB25

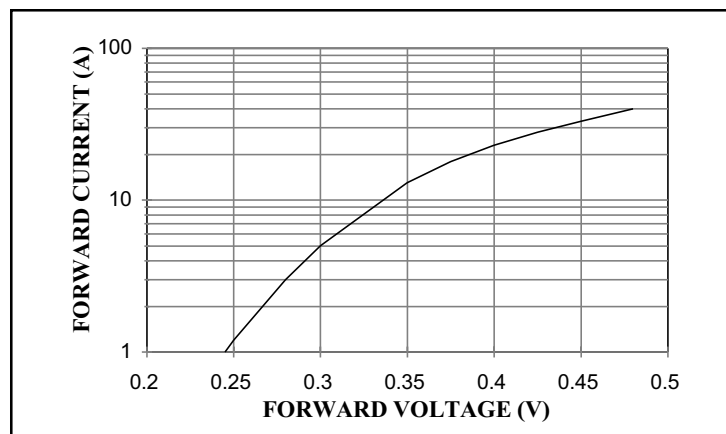


CASE OUTLINE:

P/N SED60KE25



FORWARD VOLTAGE @ $T_J = 25^\circ C$



FORWARD VOLTAGE @ $T_J = 75^\circ C$

